



SHANGHAI SEMITECH SEMICONDUCTOR CO., LTD

HF

RoHS



6KFLXXA Series

Surface Mount Transient Voltage Suppressors

Features

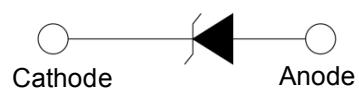
- Peak power dissipation 6000W @10 x 1000 us Pulse
- Glass passivated junction.
- Excellent clamping capability.
- High surge capability
- Low leakage current
- Low forward voltage drop
- Available in uni-directional polarity only
- $T_J = 175^\circ\text{C}$ capability suitable for high reliability and automotive requirement
- Meets ISO7637-2 surge specification (varied by test condition)
- Halogen free and RoHS compliant
- Lead-free finish

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Anode

Cathode



Anode

Mechanical Characteristics

- CASE: SOD-BLOCK Molded Plastic over glass passivated junction
- Polarity: Heatsink is Anode
- Terminal: Solder plated

Maximum Ratings and Characteristics @ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Value	Units
Peak Pulse Power Dissipation on 10/1000 us Waveform	P_{PPM}	6000	W
Peak Pulse Power Dissipation on 10/10000 us Waveform	P_{PPM}	4600	W
Power Dissipation on Infinite Heat Sink at $T_C = 25^\circ\text{C}$ (Fig. 1)	P_D	6.0	W
Peak Pulse Current of on 10/1000us Waveform	I_{PPM}	See next table	A
Peak Forward Surge Current, 8.3ms Single Half Sine-Wave (Note 1.)	I_{FSM}	500	A
Operating Junction Temperature Range	T_J	-55 to 175	°C
Storage Temperature Range	T_{STG}	-55 to 175	°C

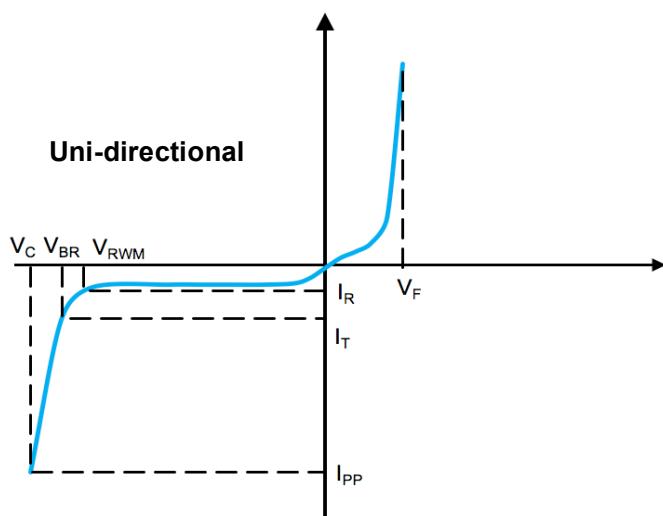
Notes:

1. Non-repetitive current pulse derated above $T_A=25^\circ\text{C}$

Electrical Specification @ Tamb 25°C

Device Type (Uni)	Reverse Stand-Off Voltage	Breakdown Voltage Min. @ I_T	Breakdown Voltage Max. @ I_T	Test Current I_T (mA)	Maximum Reverse Leakage @ V_{RMW} $T_J=175^\circ C$	Maximum Reverse Leakage @ V_{RMW} $T_J=175^\circ C$	Maximum Clamping Voltage @ I_{PP}	Maximum Peak Pulse Current @10/1000us Waveform
	$V_{RMW}(V)$	$V_{BR\ MIN}(V)$	$V_{BR\ MAX}(V)$					
6KFL10A	10.0	11.1	12.3	5	15	250	17.0	352
6KFL11A	11.0	12.2	13.5	5	10	150	18.2	329
6KFL12A	12.0	13.3	14.7	5	10	150	19.9	301
6KFL13A	13.0	14.4	15.9	5	10	150	21.5	279
6KFL14A	14.0	15.6	17.2	5	10	150	23.2	258
6KFL15A	15.0	16.7	18.5	5	10	150	24.4	245
6KFL16A	16.0	17.8	20.5	5	10	150	26.0	230
6KFL17A	17.0	18.9	20.9	5	10	150	27.6	217
6KFL18A	18.0	20.0	22.1	5	10	150	29.2	205
6KFL20A	20.0	22.2	24.5	5	10	150	32.4	185
6KFL22A	22.0	24.4	26.9	5	10	150	35.5	169
6KFL24A	24.0	26.7	29.5	5	10	150	38.9	154
6KFL26A	26.0	28.9	31.9	5	10	150	42.1	142
6KFL28A	28.0	31.1	34.4	5	10	150	45.4	132
6KFL30A	30.0	33.3	36.8	5	10	150	48.4	124
6KFL33A	33.0	36.7	40.6	5	10	150	53.3	112
6KFL36A	36.0	40.0	44.2	5	10	150	58.1	103
6KFL40A	40.0	44.4	49.1	5	10	150	64.5	93
6KFL43A	43.0	47.8	52.8	5	10	150	69.4	82.5.

※ For all types maximum $V_F = 1.8$ V at $I_F = 100$ A measured on 8.3 ms single half-sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum.

I-V Curve Characteristics

- P_{PPM}** Peak Pulse Power Dissipation - Max power dissipation
V_{RWM} Reverse Stand-off Voltage - Maximum voltage that can be applied to TVS without operation
V_{BR} Breakdown Voltage – Maximum voltage that flows through the TVS at a specified current (I_T)
V_C Clamping Voltage – Peak voltage measured across the TVS at a specified I_{PPM} (peak impulse current)
I_R Reverse Leakage Current – Current measured at V_R
V_F Forward Voltage Drop for Uni-directional

Ratings and Characteristic Curves ($T_A=25^\circ\text{C}$ unless otherwise noted)

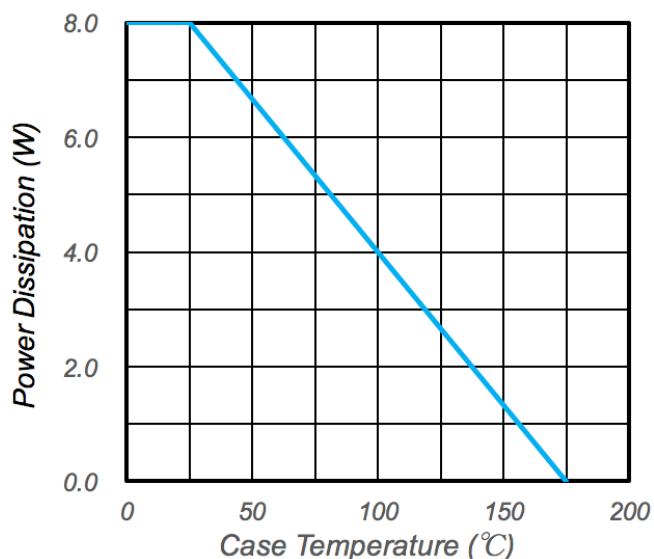


Fig. 1 - Pulse Derating Cure

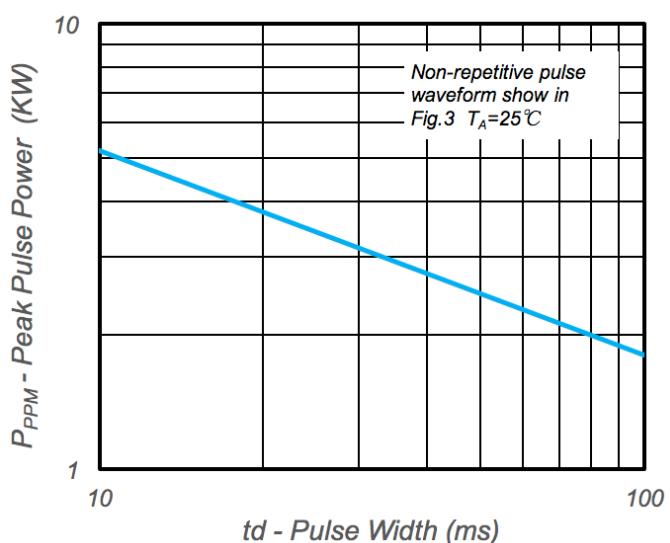


Fig. 2 - Peak Pulse Power Rating

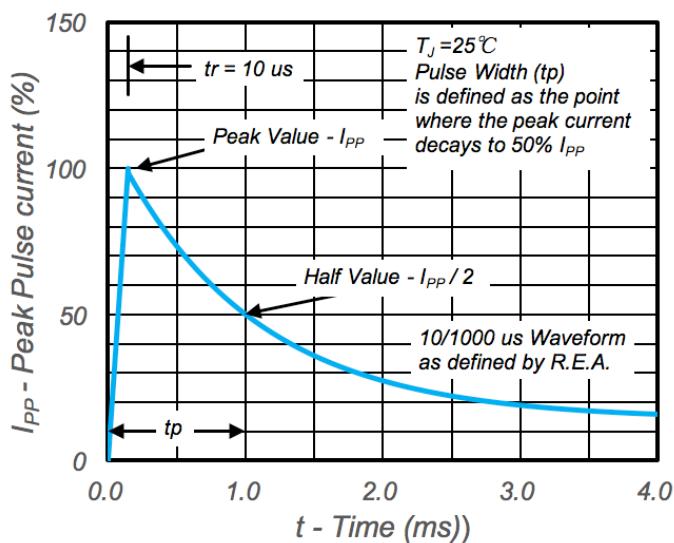


Fig. 3 – Pulse Waveform

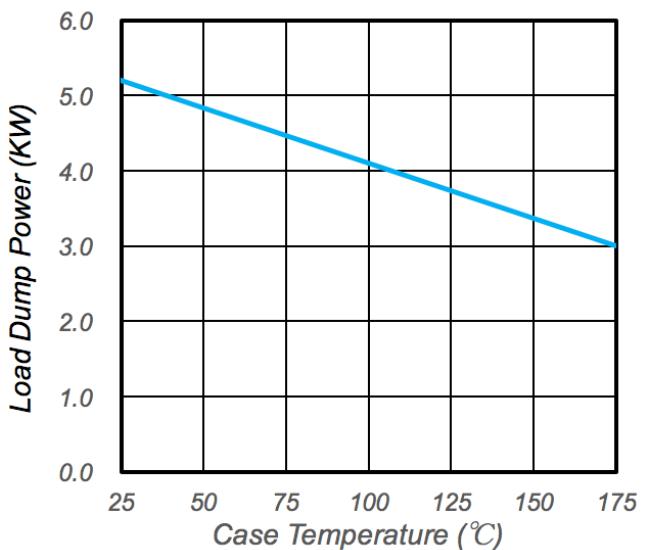
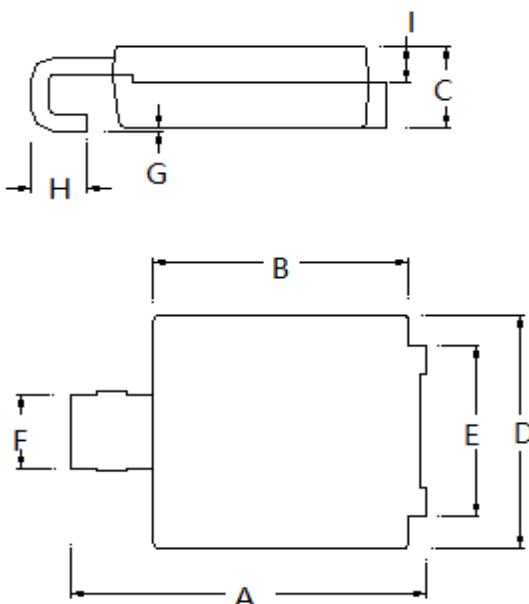


Fig. 4 – Load Dump Power Characteristics (10ms Exponential Waveform)

Package Outline Dimensions and Pad Layouts

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Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	11.59	12.19	0.456	0.480
B	8.20	8.80	0.323	0.346
C	2.60	3.20	0.102	0.126
D	7.90	8.50	0.311	0.335
E	5.70	6.30	0.224	0.248
F	2.30	2.90	0.091	0.114
G	---	0.23	---	0.009
H	1.60	2.20	0.063	0.087
I	1.00	1.60	0.039	0.063